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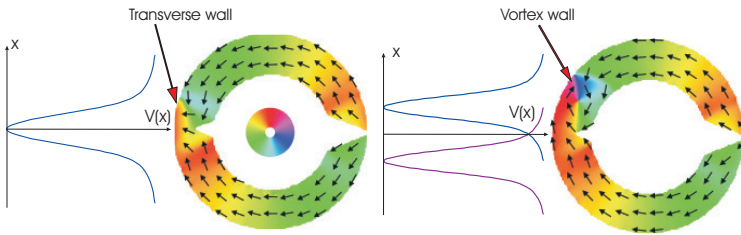
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MA 20.64

## Motivation

- A magnetic domain wall (DW) is a spatially localized variation of magnetization inside a magnetic structure.
- Depending on the lateral dimensions and material properties, two types of domain-walls appear in thin films, which are topologically not equivalent [1]: Vortex- and transverse walls.
- Domain walls behave like particles with a finite (inert) mass: The inert mass is being caused by a contraction of the DW during motion [2].
- Domain walls will interact with magnetic fields and can be manipulated with electrical currents due to several different mechanisms (momentum transfer / spin transfer / Oersted field/ hydromagnetic force) [3].
- The shape of a magnetic element will form a potential landscape for DWs due to the change in energy of a wall at different positions (e.g. structure width).
- Nanoconstrictions will cause a potential  $V$  which might be attractive (transverse wall) or repulsive (vortex wall):

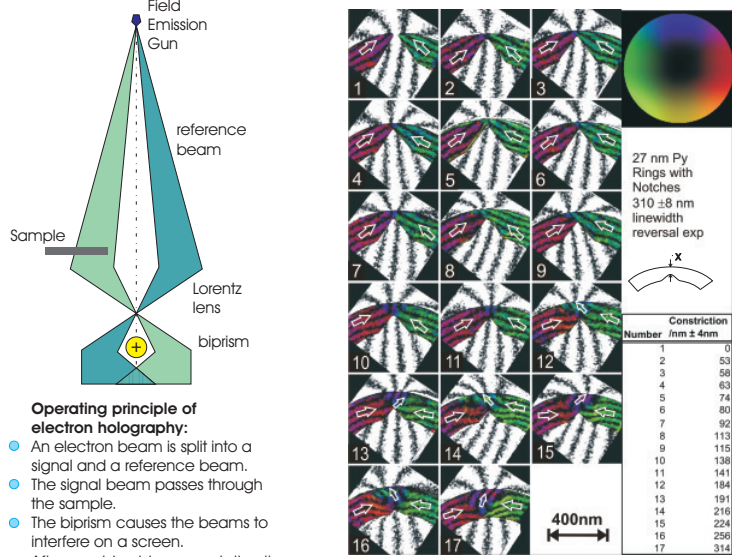


- Transverse walls are attracted by a constriction while vortex-walls are repelled by the constriction.
- In the case of spatial symmetry around the minimum the potential  $V$  can be calculated from the cycle duration  $T$  for different energies  $E$  as for the classical anharmonic oscillator:

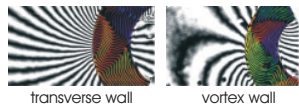
$$x(V) = \frac{1}{2\pi\sqrt{2m}} \int_0^V \frac{T(E)dE}{\sqrt{U-E}}$$

## Imaging of DW in Constrictions

- PEEM (for results see MA 20.117), SEMPA, electron holography



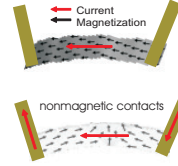
- Electron holographic image series showing domain walls in constrictions of different sizes.
- The smaller the constriction width  $x$  the smaller the domain wall.
- The insert shows the direction of the magnetic field.



## References

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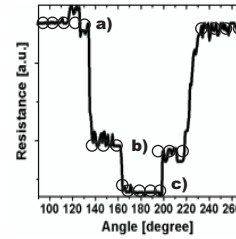
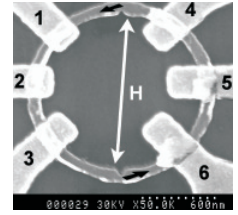
## Determination of the Potential Landscape



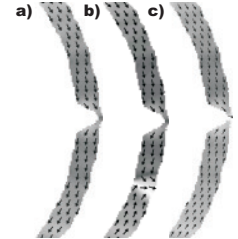
No domain wall between contacts: Magnetization parallel to the current  $\Rightarrow$  high resistance due to (A)MR.

Domain Wall between contacts: Magnetization perpendicular to the current:  $\Rightarrow$  low resistance [4].

- Ring geometry: diameter = 0.5-2  $\mu$ m, width = 100-300 nm
- Nonmagnetic contacts (10 nm Ti, 100 nm Au), fabricated by lift-off technique



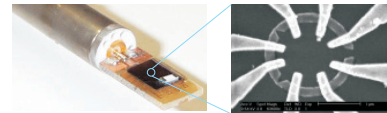
Direction of the external magnetic field for the three configurations: 180°, 90°, and another 90°.



- Resistance measurements at remanence after saturation along different directions.
- Three distinct resistance levels are observed corresponding to the configurations a), b), c).
- The attractive potential well of the notch extends far beyond the physical dimensions [5].
- Simulation of the AMR signal by calculating the current distribution and magnetization configuration.
- Experimental and calculated resistance between contacts 3 and 6 shows a drop as the domain wall is pinned at the notch [5].
- By measuring the resistance the position of the domain wall with respect to the constriction can be determined.

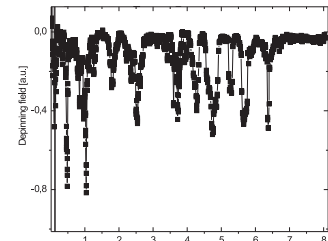
## Microwave Excitation of DW in Rings

- For the following measurements the DW resistance has to be measured while injecting an RF field. The rings will be positioned in the H-field maximum of a coplanar waveguide while measuring the resistance using several nonmagnetic contacts. The sample can be cooled down to about 2 K and is located inside a vector magnet which allows a rotation of the external magnetic field.

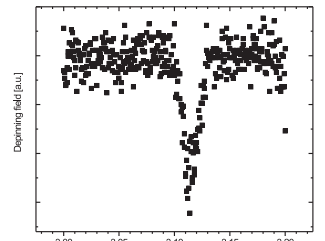


**Sample holder:** The ferromagnetic ring is located on a coplanar waveguide fabricated from silicon. The white square is a termination resistor. Electrical contact is established through wire-bonding.

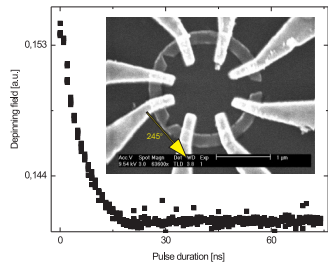
- For the following measurements a Co-ring with a width of 200 nm and an outer diameter of 2  $\mu$ m has been used. The film thickness is 30 nm.



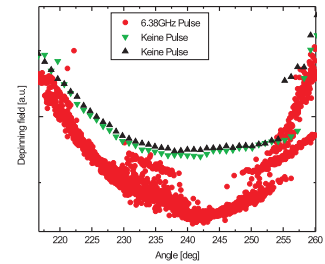
Depinning field as a function of microwave frequency. At resonance the field necessary is reduced by 15%.



Detail from the left figure. FWHM of the resonance line is about 10 MHz.



Depinning field at the resonance frequency 6.38 GHz as a function of microwave pulse duration.



Depinning field as a function of the angle of the external field. At an angle of 245° the field needed for lifting the DW out of the potential well is minimal because the field is perpendicular to the DW.

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